

TC74VHC573F, TC74VHC573FW, TC74VHC573FT**OCTAL D-TYPE LATCH WITH 3-STATE OUTPUT**

The TC74VHC573 is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and a output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES:

- High Speed $t_{pd} = 4.5\text{ns}$ (typ.) at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}$ (Max.) at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range... V_{CC} (opr) = 2V~5.5V
- Low Noise $V_{OLP} = 1.2\text{V}$ (Max.)
- Pin and Function Compatible with 74ALS573

TRUTH TABLE

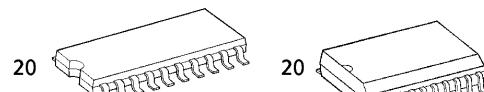
INPUTS			OUTPUT
\overline{OE}	LE	D	
H	X	X	Z
L	L	X	Q_n
L	H	L	L
L	H	H	H

X : Don't Care

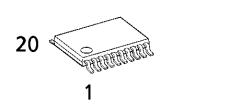
Z : High Impedance

Q_n : Q outputs are latched at the time when the LE input is taken to a low logic level.

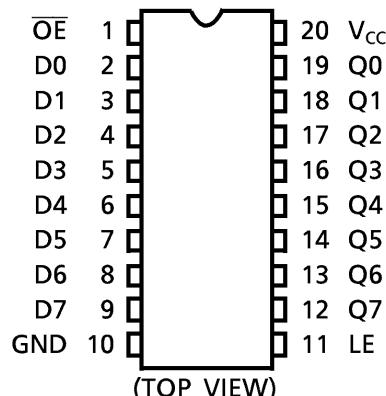
(Note) The JEDEC SOP (FW) is not available in Japan.



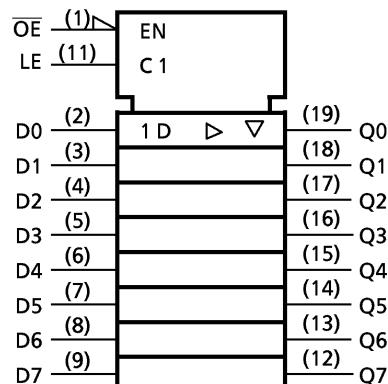
F (SOP20-P-300-1.27) FW (SOL20-P-300-1.27)
Weight : 0.22g (Typ.) Weight : 0.46g (Typ.)



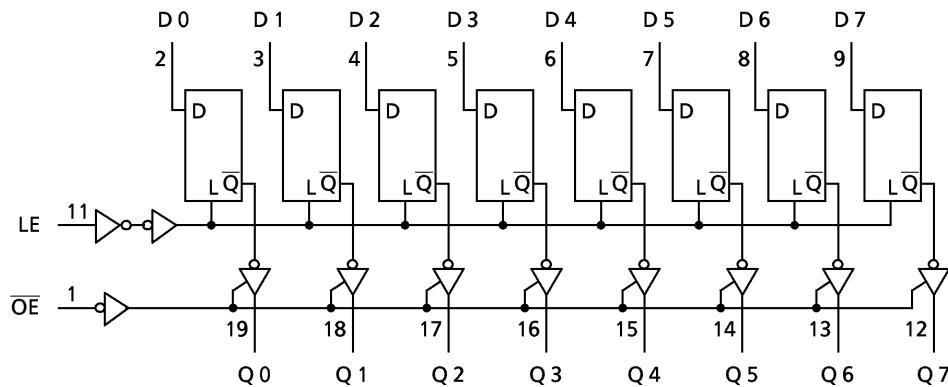
FT (TSSOP20-P-0044-0.65)
Weight : 0.08g (Typ.)

PIN ASSIGNMENT

(TOP VIEW)

IEC LOGIC SYMBOL

SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~ V_{CC} + 0.5	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt/dv	0~100 ($V_{CC} = 3.3 \pm 0.3V$) 0~20 ($V_{CC} = 5 \pm 0.5V$)	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		2.0 3.0~ 5.5	1.50 $V_{CC} \times 0.7$	—	—	1.50 $V_{CC} \times 0.7$	—	V
Low - Level Input Voltage	V_{IL}		2.0 3.0~ 5.5	— —	— $V_{CC} \times 0.3$	0.50	— —	0.50 $V_{CC} \times 0.3$	V
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	V
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	— —	— —	2.48 3.80	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50\mu A$	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	V
			$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	— —	— —	0.36 0.36	— —	
3 - State Output Off - State Current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND	5.5	—	—	—	± 0.25	—	± 2.50
Input Leakage Current	I_{IN}	$V_{IN} = 5.5V$ or GND	0~5.5	—	—	—	± 0.1	—	± 1.0
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C		Ta = -40~85°C		UNIT
				TYP.	LIMIT	LIMIT	LIMIT	
Minimum Pulse Width (LE)	$t_{W(H)}$		3.3 ± 0.3	—	5.0	5.0	ns	
			5.0 ± 0.5	—	5.0	5.0		
Minimum Set-up Time	t_s		3.3 ± 0.3	—	3.5	3.5	ns	
			5.0 ± 0.5	—	3.5	3.5		
Minimum Hold Time	t_h		3.3 ± 0.3	—	1.5	1.5	ns	
			5.0 ± 0.5	—	1.5	1.5		

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (LE-Q)	t_{pLH} t_{pHL}	3.3 ± 0.3 5.0 ± 0.5	15	—	7.6	11.9	1.0	14.0	ns
			50	—	10.1	15.4	1.0	17.5	
			15	—	5.0	7.7	1.0	9.0	
			50	—	6.5	9.7	1.0	11.0	
Propagation Delay Time (D-Q)	t_{pLH} t_{pHL}	3.3 ± 0.3 5.0 ± 0.5	15	—	7.0	11.0	1.0	13.0	ns
			50	—	9.5	14.5	1.0	16.5	
			15	—	4.5	6.8	1.0	8.0	
			50	—	6.0	8.8	1.0	10.0	
3-State Output Enable Time	t_{pZL} t_{pZH}	3.3 ± 0.3 5.0 ± 0.5	15	—	7.3	11.5	1.0	13.5	
			50	—	9.8	15.0	1.0	17.0	
			15	—	5.2	7.7	1.0	9.0	
			50	—	6.7	9.7	1.0	11.0	
3-State Output Disable Time	t_{pLZ} t_{pHZ}	3.3 ± 0.3 5.0 ± 0.5	50	—	10.7	14.5	1.0	16.5	pF
			50	—	6.7	9.7	1.0	11.0	
Output to Output Skew	t_{osLH} t_{osHL}	3.3 ± 0.3 5.0 ± 0.5	50	—	—	1.5	—	1.5	
			50	—	—	1.0	—	1.0	
Input Capacitance	C _{IN}				—	4	10	—	10
Output Capacitance	C _{OUT}				—	6	—	—	—
Power Dissipation Capacitance	C _{PD}	(Note 2)			—	29	—	—	—

Note (1) Parameter guaranteed by design. $t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLM} - t_{pHLn}|$

Note (2) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per Latch)}$$

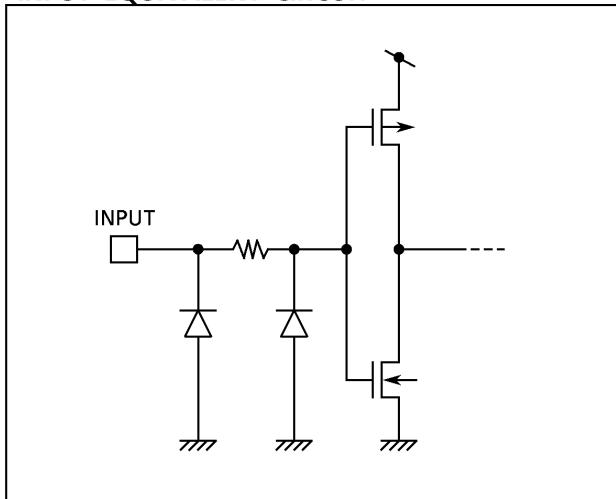
And the total C_{PD} when n pcs. of Latch operate can be gained by the following equation :

$$C_{PD}(\text{total}) = 21 + 8 \cdot n$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

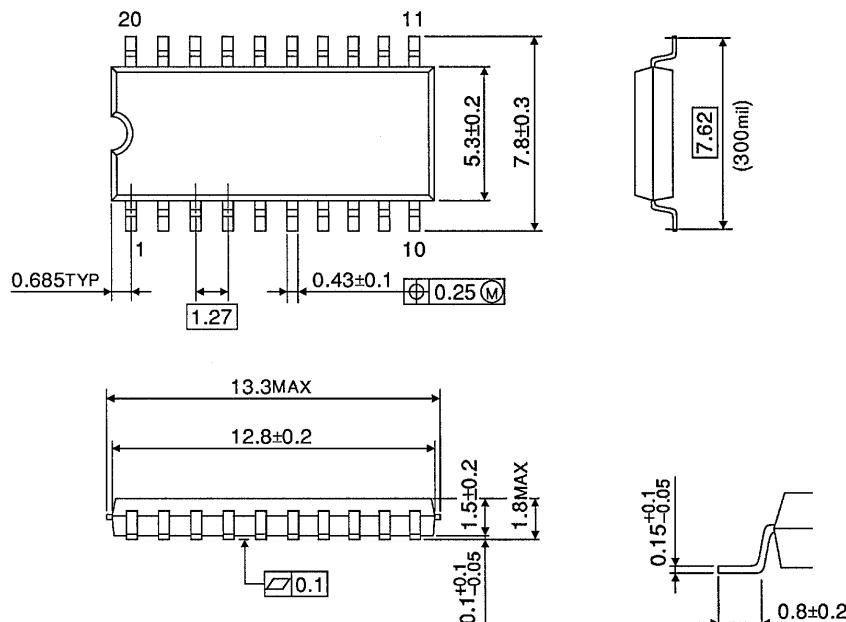
PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			UNIT
		V _{CC} (V)		TYP.	MAX.		
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.8 (0.9)	1.0 (1.2)		V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.8 (-0.9)	-1.0 (-1.2)		V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	—	3.5		V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	—	1.5		V

(Note) The value in () only applies to JEDEC SOP (FW) devices.

INPUT EQUIVALENT CIRCUIT

SOP 20PIN (200mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27)

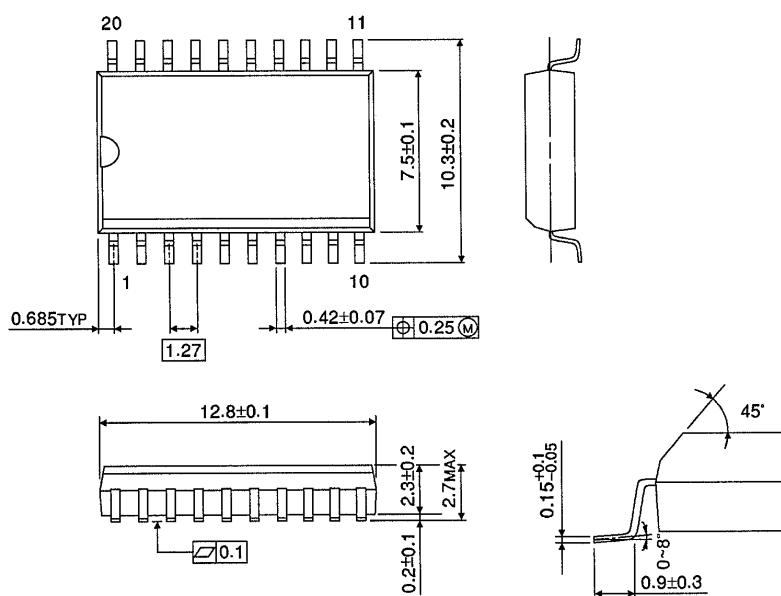
Unit in mm



SOP 20PIN (300mil BODY) PACKAGE DIMENSIONS (SOL20-P-300-1.27)

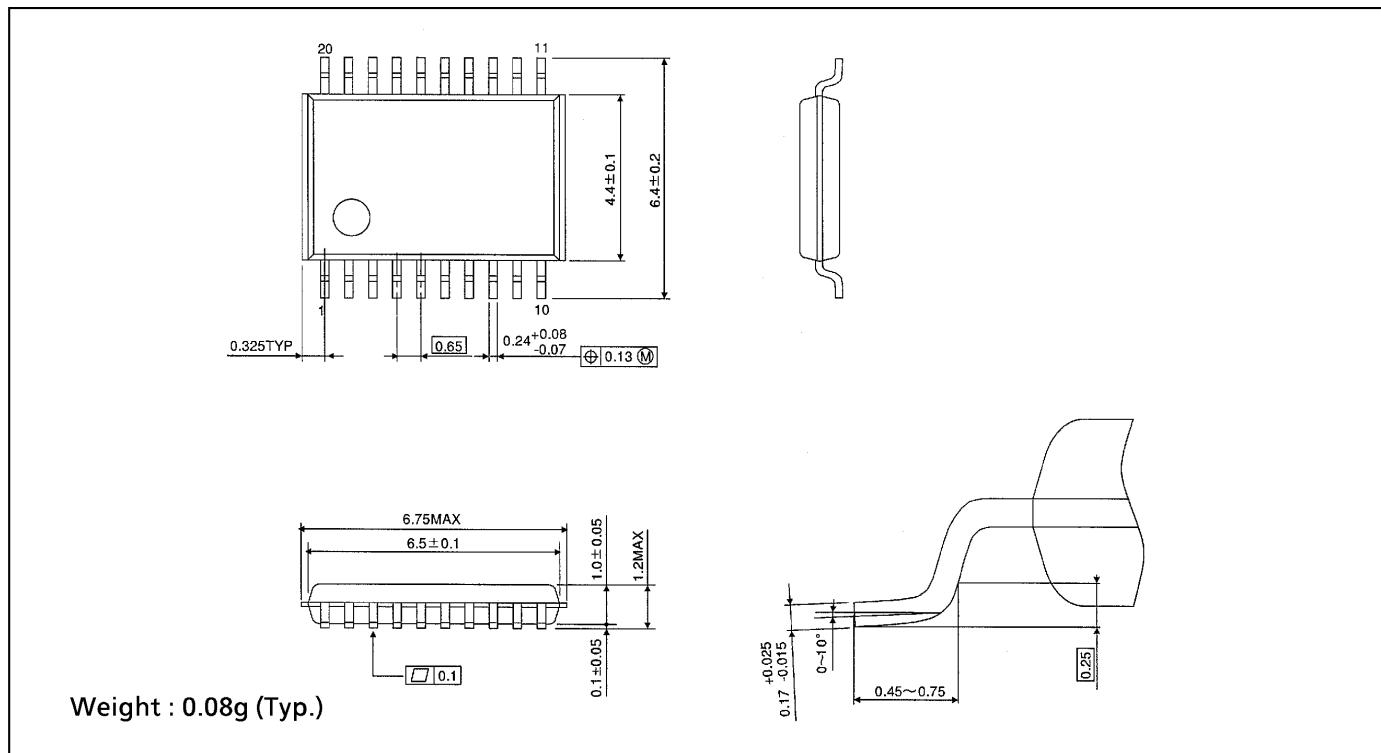
Unit in mm

(Note) This package is not available in Japan.



TSSOP 20PIN PACKAGE DIMENSIONS (TSSOP20-P-0044-0.65)

Unit in mm



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